
Wide Bandgap Semiconductor Materials and Devices 19

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Table of Contents

Preface *iii*

Chapter 1 **Electronics and Photonics Division Award Address**

(Electronics and Photonics Division Award Address) Performance of
InGaN/GaN-Based Light Emitting Diodes Fabricated with ZnO Nanorods 3
K. S. Kim, S. Song, T. Y. Seong

Chapter 2 **GaN Devices**

Influence of Size Reduction and Current Density on the Optoelectrical Properties of
Green III-Nitride Micro-LEDs 13
D. H. Kim, T. Y. Seong

Chapter 3 **Ultra-Wide Bandgap Materials and Devices**

(Invited) Fabrication and Characterization of β -Ga₂O₃ Heterojunction Rectifiers 21
M. J. Tadjer, L. E. Luna, E. Cleveland, K. D. Hobart, F. J. Kub

Interface State Density of Atomic Layer Deposited Al₂O₃ on β -Ga₂O₃ 27
C. Y. Su, T. Hoshii, I. Muneta, H. Wakabayashi, K. Tsutsui, H. Iwai, K. Kakushima

Chapter 4
Poster Session

Wide Color Gamut Deep-Blue OLED Architecture for Display Application <i>D. K. Dubey, R. K. Konidena, S. Sahoo, R. A. K. Yadav, S. S. Swayamprabha, K. R. J. Thomas, J. H. Jou</i>	33
Ultraviolet Sensor Performance of Nanostructured LaCoO ₃ Prepared by the Solution-Polymerization Method <i>C. R. Michel, M. A. Lopez-Alvarez, A. H. Martinez-Preciado</i>	41
AlGaIn/GaN High Electron Mobility Transistors with a p-GaN Backgate Structure <i>W. T. Lin, W. C. Lin, Y. N. Zhong, Y. M. Hsin</i>	49
AlGaIn/GaN High Electron Mobility Transistors with a p-Type GaN Cap Layer <i>H. C. Tsai, S. C. Fan Chiang, Y. N. Zhong, Y. M. Hsin</i>	53
The Effect of Threading Dislocation on Current-Voltage Characteristics of 3.3 kV 4H-SiC Schottky Barrier Diode <i>M. Na, J. Keum, J. H. Moon, I. H. Kang, W. Bahng</i>	59
Effect of Phosphor Layer Size on the Optical and Thermal Properties of Chip Scale Packaged Light-Emitting Diodes <i>G. H. Bak, S. W. Oh, H. H. Sung, S. B. Yoon, W. J. Kim, H. H. Jeong, J. O. Song, T. Y. Seong</i>	67

Chapter 5
Silicon Carbide

(Invited) SiC Lateral MOSFETs Implemented on Semi-Insulating Substrate <i>H. W. Kim, O. Seok, J. H. Moon, W. Bahng, J. Jo</i>	75
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Chapter 6
Wide Bandgap Oxides

(Invited) Electrochemistry of Transition Metal Oxide Based Mountable Electrochromic Devices <i>B. Deb, P. T. Gayathri, S. Sajitha</i>	91
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Rapid Synthesis of Semipolar ZnO Nanorod Arrays on <i>M</i> -Sapphire by Microwave-Assisted Chemical Bath Deposition <i>C. J. Tsai, H. Do, C. Chang, K. A. Chiu, C. C. Hsiang, L. Chang</i>	107
Effect of Substrates on Structural Properties of Pure Anatase Phase Titanium Dioxide Thin Films Prepared by Mist Chemical Vapor Deposition <i>Q. Zhang, C. Li</i>	113
Author Index	119